TOSHIBA

TOSHIBA HIGH EFFICIENCY RECTIFIER (HED) SILICON EPITAXIAL JUNCTION TYPE

U1DL44A

SWITCHING TYPE POWER SUPPLY APPLICATIONS

• Repetitive Peak Reverse Voltage : V_{RRM}=200V

• Average Forward Current : I_{F(AV)}=1.0A

• Very Fast Reverse-Recovery Time : t_{rr}=35ns (Max.)

• Low Forward Voltage : V_{FM}=0.98V

Available to Reduce Switching Losses and Output Noise

• Surface Mounting Plastic Mold Package

MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Repetitive Peak Reverse Voltage	v_{RRM}	200	V	
Average Forward Current	I _{F (AV)}	1.0	Α	
Peak One Cycle Surge Forward		10 (50Hz)		
Current (Non-Repetitive)	$I_{ ext{FSM}}$	11 (60Hz)	A	
Junction Temperature	T_j	-40~150	$^{\circ}\mathrm{C}$	
Storage Temperature	$\mathbf{T}_{ ext{stg}}$	-40~150	°C	

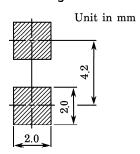
Unit in mm 2 1. ANODE 2. CATHODE JEDEC EIAJ TOSHIBA 3-4D1A

Weight: 0.06g

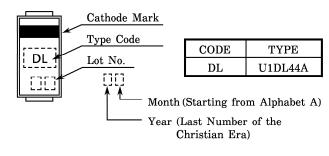
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Peak Forward Voltage	$ m v_{FM}$	$I_{\text{FM}} = 1.0 A$	_		0.98	V
Repetitive Peak Reverse Current	$I_{ m RRM}$	$V_{ m RRM}$ =200 V	_	1	10	μ A
Reverse Recovery Time	t _{rr}	$I_{\rm F} = 1A$, di/dt= $-30A/\mu s$	_	_	35	ns
Forward Recovery Time	t _{fr}	$I_{\mathbf{F}} = 1.0 A$	_	_	100	ns

Standard Soldering Pad

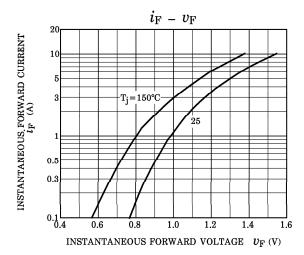


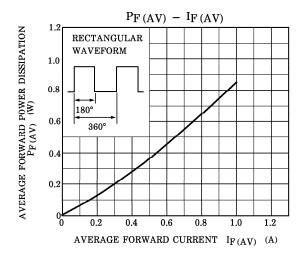
MARKING

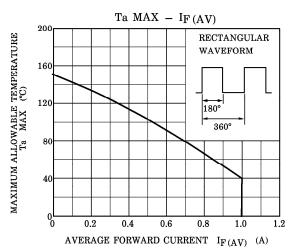


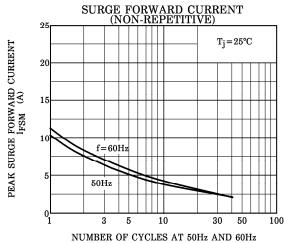
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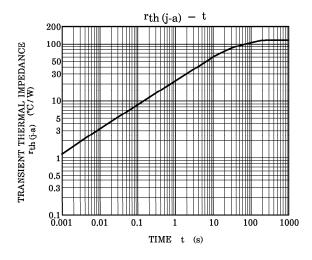
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